

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	187	gate same (silicon or Si) near3 percent	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/13 15:43
L3	1	gate same (wt adj percent or weight adj perecent) near3 (Si or silicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/13 15:49
L4	299	(wt adj percent or weight adj perecent) near3 (Si or silicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/13 16:08
L5	13	gate adj electrode near2 schottky adj characteristic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/13 16:22
L6	16	gate adj electrode near3 schottky adj characteristic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/13 16:22